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# 74LVQ00

### Absolute Maximum Ratings(Note 1)

Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Input Diode Current (IIK)	
$V_{I} = -0.5V$	–20 mA
$V_{I} = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (VI)	$-0.5 V$ to $V_{CC} + 0.5 V$
DC Output Diode Current (I <sub>OK</sub> )	
$V_{O} = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V <sub>O</sub> )	–0.5V to $V_{CC}^{} + 0.5V$
DC Output Source or Sink Current $(I_O)$	±50 mA
DC V <sub>CC</sub> or Ground Current	
(I <sub>CC</sub> or I <sub>GND</sub> )	±200 mA
Storage Temperature (T <sub>STG</sub> )	$-65^{\circ}C$ to $+150^{\circ}C$
DC Latch-Up Source or Sink Current	±100 mA

#### **Recommended Operating** Conditions (Note 2)

Supply Voltage (V <sub>CC</sub> )	2.0V to 3.6V
Input Voltage (V <sub>I</sub> )	0V to $V_{CC}$
Output Voltage (V <sub>O</sub> )	0V to $V_{CC}$
Operating Temperature (T <sub>A</sub> )	$-40^\circ C$ to $+85^\circ C$
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
V <sub>IN</sub> from 0.8V to 2.0V	
V <sub>CC</sub> @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which Note 1: The Absolute maximum Ratings are mose values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions the actual during expecting. for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

## **DC Electrical Characteristics**

Symbol	Parameter	V <sub>CC</sub>	<b>T</b> <sub>A</sub> = +	-25°C	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	Units	Conditions
Symbol	Falameter	(V)	Тур	Gua	ranteed Limits	Onits	Conditions
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	v	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
V <sub>OH</sub>	Minimum High Level	3.0	2.99	2.9	2.9		I <sub>OUT</sub> = -50 μA
	Output Voltage	3.0		2.58	2.48	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -12 \text{ mA} \text{ (Note 3)}$
V <sub>OL</sub>	Maximum Low Level	3.0	0.002	0.1	0.1		I <sub>OUT</sub> = 50 μA
	Output Voltage	3.0		0.36	0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 12 \text{ mA} \text{ (Note 3)}$
I <sub>IN</sub>	Maximum Input Leakage Current	3.6		±0.1	±1.0	μΑ	$V_I = V_{CC}, GND$
I <sub>OLD</sub>	Minimum Dynamic	3.6			36	mA	V <sub>OLD</sub> = 0.8V Max (Note 5)
IOHD	Output Current (Note 4)	3.6			-25	IIIA	V <sub>OHD</sub> = 2.0V Min (Note 5)
I <sub>CC</sub>	Maximum Quiescent Supply Current	3.6		2.0	20.0	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	0.6	1.0		V	(Note 6)(Note 7)
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.5	-1.0		V	(Note 6)(Note 7)
V <sub>IHD</sub>	Maximum High Level Dynamic Input Voltage	3.3	1.5	2.0		V	(Note 6)(Note 8)
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage	3.3	1.5	0.8		V	(Note 6)(Note 8)

3: All outpu aded: thres s on input :

Note 4: Maximum test duration 2.0 ms. one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as  $75\Omega$  for commercial temperature range is guaranteed for 74LVQ. Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n - 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (VILD), 0V to threshold  $(V_{IHD}), f = 1 MHz.$ 

## **AC Electrical Characteristics**

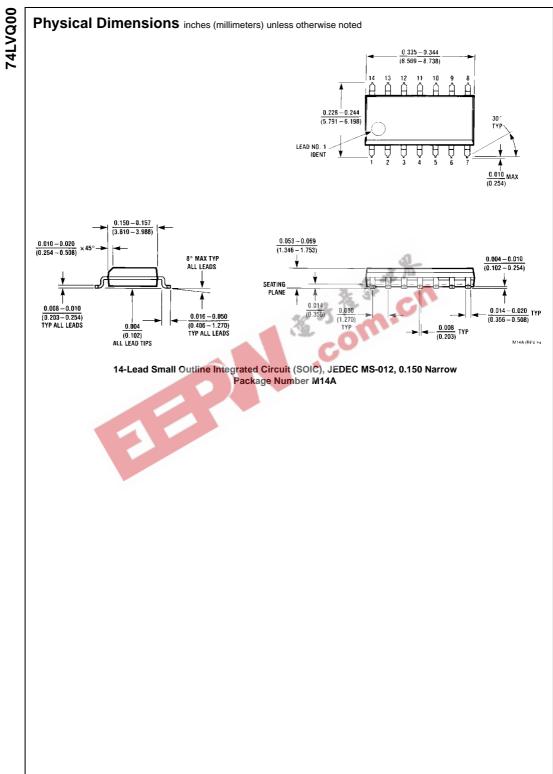
AC Electrical Characteristics								
				$T_A = +25^{\circ}C$		T <sub>A</sub> = -40°	C to +85°C	
Symbol	Parameter	Vcc	C <sub>L</sub> = 50 pF		C <sub>L</sub> = 50 pF C <sub>L</sub> = 50 p		C <sub>L</sub> = 50 pF	
		(V)	Min	Тур	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	2.7	2.0	8.4	13.4	2.0	14.0	
		$3.3\pm 0.3$	2.0	7.0	9.5	2.0	10.0	ns
t <sub>PHL</sub>	Propagation Delay	2.7	1.5	6.6	11.3	1.0	12.0	
		$3.3\pm 0.3$	1.5	5.5	8.0	1.0	8.5	ns
t <sub>OSHL,</sub>	Output to Output Skew	2.7		1.0	1.5		1.5	20
t <sub>OSLH</sub>	(Note 9)	$3.3\pm 0.3$		1.0	1.5		1.5	ns

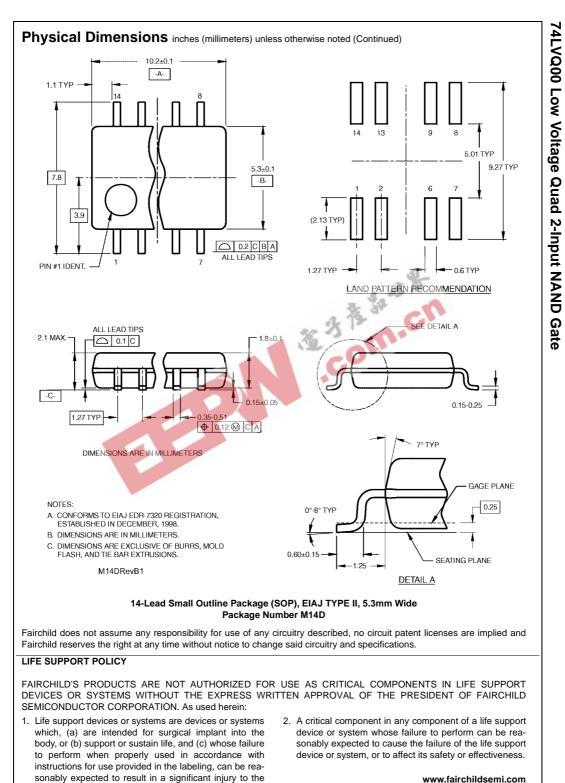
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

### Capacitance

Symbol	Parameter	Тур	Units	Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = Open
C <sub>PD</sub> (Note 10)	Power Dissipation Capacitance	22	pF	V <sub>CC</sub> = 3.3V
Note 10: C <sub>PD</sub> is	s measured at 10 MHz.		後 、CO	Sa a A

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